



# The End of High Priced ASICs.

Disruptive Via-Only™ Technology Makes it Possible.



RAD HARD

## Size, Weight and Power are Critical for Defense Applications

Defense industry applications such as secure software defined radios, man-packs, avionics, satellites, munitions, electronic vehicle health systems and mechanized vehicle electronics require small, light weight, and low power electronics. ASIC integration of electronics has been a key way to achieve size, weight, and power reductions while maintaining mission-critical performance and tamper-protecting critical electronics.

Unfortunately, mixed signal full-custom ASIC development has been an expensive, time-consuming, and risky endeavor.

### VCA Technology Benefits

- Cut development time by 70%
- Cut development cost by 75%
- Low Risk
- 4-Week Fabrication
- IP Reuse

## Announcing the End of High Priced ASICs

Triad's disruptive Via-Configurable Array (VCA) technology is a new way to design mixed signal ASICs using a single mask Via-Only™ fabrication process.

VCAs combine silicon proven analog and digital tiles on an integrated circuit die. These tiles are overlaid with a global routing fabric which covers the digital, memory, and analog resources throughout the VCA.

Vias placed between two of the metal layers are used to interconnect and configure all of the mixed signal resources throughout the VCA.

Wafers containing VCA die are partially processed at the foundry up to the via layer and these wafers are then staged at the foundry. Your mixed signal design is processed by TRIAD's patented design tools and converted into a single Via-Only™ mask which is then sent to the foundry to be processed against the staged wafers.

## Defense Focused Engineering

- ITAR Compliant & 100% US-Citizens
- ASIC Design Experts with over 120 years experience
- 100+ Successful ASIC tape outs

## Radiation-Hardened Arrays

- Via Configurable Digital & Mixed Signal Rad-Hard Arrays
- Rad-Hard by Process & Rad-Hard by Design Arrays
- Total Incident Dosage (TID) > 1 Meg rad
- We can create a custom Rad-Hard VCA for a specific application space

## Analog Building Blocks

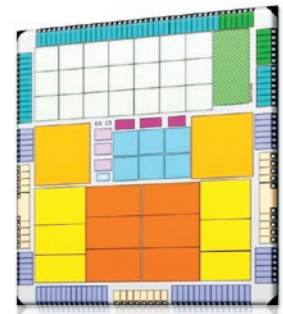
- Band gap, Brown-out detector
- Biquad sections
- Arrays of capacitors, resistors,
- Continuous time & switched switches, & transistors capacitor filters, Capacitive touch interface
- Op-amps, comparators, integrators, Sigma delta modulators

## Data Converters

- High speed ADCs and DACs
- 8 to 24-bits resolutions

## VCA Technology

- 5,000 to 1-million ASIC gates
- Distributed and block RAMs
- 1-KB to 128-KB EEPROM
- Configurable analog & digital I/O
- ARM® Cortex™-M0 32-bit Processor
- USB 1.1, USB 2.0
- IIC, SPI, UART, LIN, CAN
- Digital filters, FFT
- PLLs, delay lines, real-time-clock



VCA assembled from mixed signal building blocks.

## Power Management

- 1.8V to 70V operation
- LDO, buck-boost regulator, charge pump
- LED driver, H-bridge, motor control

## Getting Started

Whether you are using one of TRIAD's existing arrays or having us create an optimized array for your application, the best way to get started is to have one of our FAEs take a look at your design and help you explore your options. To get more information about getting your design on a VCA, email an FAE at [info@triadsemi.com](mailto:info@triadsemi.com) or give us a call at 336-774-2150.

## VCA Selector Guide

| Array   | ASIC Gates | RAM     | NVM          | Digital I/O | Analog I/O | Analog IP  |
|---------|------------|---------|--------------|-------------|------------|--|
| VCA-1   | 40,000     | 54-Kb   | 18-KB ROM    | 72          | 42         | 30+ op-amps plus discrete R,C, transistors. 2 8-bit DACs, 1 10-bit DAC. Band-gap, vref – 5V operation...                 |
| VCA-2   | 9,000      | 12-Kb   | 1-KB EEPROM  | 42          | 48         | 50V operation, 6 20V op-amp tiles, 1 50V ref tile, 6 50V regulator tiles, 4 3.6V op-amp tiles, 4 8-bit ADCs...           |
| VCA-3   | 16,800     | 12-Kb   | –            | 14          | 22         | 4 3.3V op-amp tiles, 2 fully differential op-amp tiles, 3 10-bit DACs, 1 8-bit ADC, band-gap                             |
| VCA-4   | 20,000     | 19-Kb   | 8-KB EEPROM  | 32          | 59         | 6 low-power, low-noise op-amp tiles, 2 fully differential op-amp tiles, band-gap, bias gen, 2 hi-resistance tiles, PLL   |
| VCA-5   | 76,000     | 102-Kb  | 32-KB EEPROM | 60          | 72         | 16 fully differential op-amp tiles, 20 3.3V op-amp tiles, 12 wideband tiles, 8 10-bit DACs, 10-bit 25MSPS ADC, DAC array |
| VCA-6   | 800,000    | 1.14-Mb | –            | 320         | 100        | High speed pipelined ADC arrays, current steering DACs. 9 fully differential op-amp tiles, 12 3.3V op-amp tiles          |
| VCA-201 | 385,000    | 380-Kb  | 46-KB ROM    | 239         | –          | RAD-HARD digital only, mixed signal 2nd half 2010. PCI I/O, LVDS I/O, CMOS-SOI, Dual Oscillators, TID > 1 M rad          |
| Mocha-1 | 22,000     | 30-Kb   | 16-KB EEPROM | 88          | 88         | ARM Cortex-M0 32-bit processor with 8 fully differential op-amp tiles, 6 3.3V op-amp tiles, band gap, 3 10-bit DACs      |